

# RT1P144X SERIES

Transistor

Transistor With Resistor

For Switching Application

Silicon PNP Epitaxial Type

## DESCRIPTION

RT1P144X is a one chip transistor with built-in bias resistor,NPN type is RT1N144X.

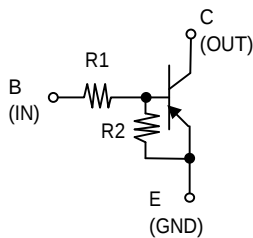
## FEATURE

- Built-in bias resistor ( $R1=10k\Omega$ , $R2=47k\Omega$ ).

## APPLICATION

Inverted circuit,switching circuit,interface circuit, driver circuit.

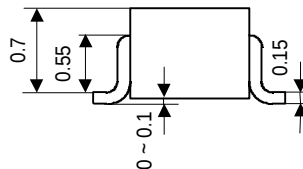
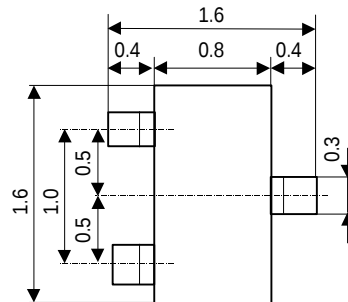
Equivalent circuit



## OUTLINE DRAWING

UNIT: mm

RT1P144U



JEITA: -

JEDEC: -

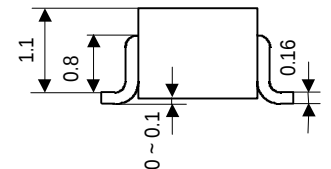
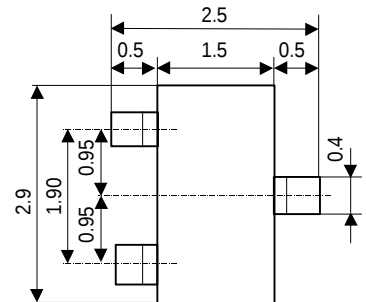
Terminal Connector

: Base

: Emitter

: Collector

RT1P144C



JEITA: SC-59

JEDEC: Similar to TO-236

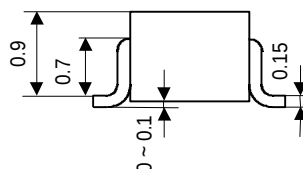
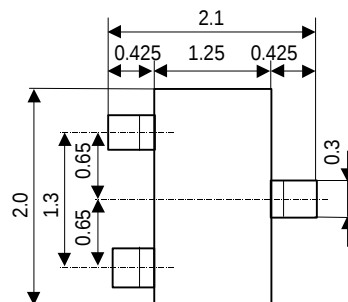
Terminal Connector

: Base

: Emitter

: Collector

RT1P144M



JEITA: SC-70

JEDEC: -

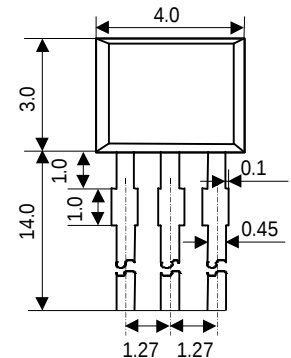
Terminal Connector

: Base

: Emitter

: Collector

RT1P144S



JEITA: -

JEDEC: -

Terminal Connector

: Emitter

: Collector

: Base

# RT1P144X SERIES

Transistor

Transistor With Resistor

For Switching Application

Silicon PNP Epitaxial Type

## MAXIMUM RATING (Ta=25 °C)

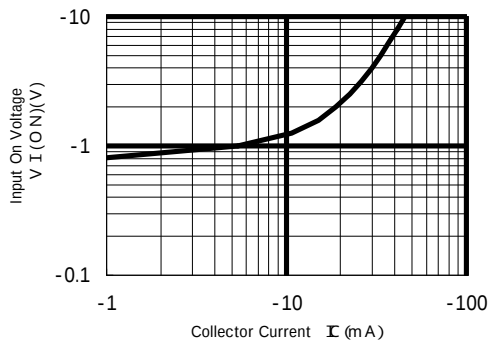
| SYMBOL           | PARAMETER                       | RATING     |            |          |          | UNIT |
|------------------|---------------------------------|------------|------------|----------|----------|------|
|                  |                                 | RT1P144U   | RT1P144M   | RT1P144C | RT1P144S |      |
| V <sub>CBO</sub> | Collector to Base voltage       | -50        |            |          |          | V    |
| V <sub>EBO</sub> | Emitter to Base voltage         | -6         |            |          |          | V    |
| V <sub>CEO</sub> | Collector to Emitter voltage    | -50        |            |          |          | V    |
| I <sub>C</sub>   | Collector current               | -100       |            |          |          | mA   |
| I <sub>CM</sub>  | Peak Collector current          | -200       |            |          |          | mA   |
| P <sub>C</sub>   | Collector dissipation(Ta=25 °C) | 150        | 200        |          | 450      | mW   |
| T <sub>j</sub>   | Junction temperature            | +150       | +150       |          |          |      |
| T <sub>stg</sub> | Storage temperature             | -55 ~ +150 | -55 ~ +150 |          |          |      |

## ELECTRICAL CHARACTERISTICS (Ta=25 °C)

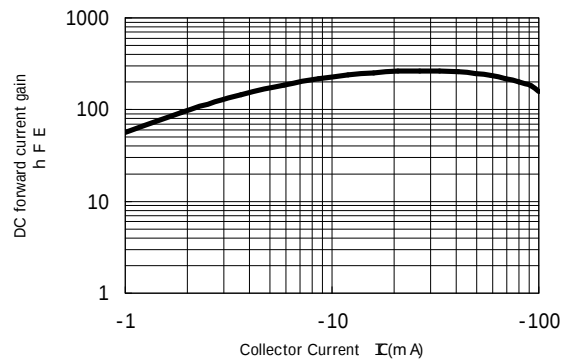
| SYMBOL        | PARAMETER                 | TEST CONDITION                      | LIMIT |      |      | UNIT       |
|---------------|---------------------------|-------------------------------------|-------|------|------|------------|
|               |                           |                                     | MIN   | TYP  | MAX  |            |
| $V_{(BR)CEO}$ | C to E break down voltage | $I_C = -100 \mu A, R_{BE} = \infty$ | -50   |      |      | V          |
| $I_{CBO}$     | Collector cut off current | $V_{CB} = -50V, I_E = 0$            |       |      | -0.1 | $\mu A$    |
| $h_{FE}$      | DC forward current gain   | $V_{CE} = -5V, I_C = -5mA$          | 50    |      |      | -          |
| $V_{CE(sat)}$ | C to E saturation voltage | $I_C = -10mA, I_B = -0.5mA$         |       | -0.1 | -0.3 | V          |
| $V_{I(ON)}$   | Input on voltage          | $V_{CE} = -0.2V, I_C = -5mA$        |       | -1.2 | -1.8 | V          |
| $V_{I(OFF)}$  | Input off voltage         | $V_{CE} = -5V, I_C = -100 \mu A$    | -0.4  | -0.7 |      | V          |
| $R_1$         | Input resistance          |                                     | 7     | 10   | 13   | k $\Omega$ |
| $R_2 / R_1$   | Resistance ratio          |                                     | 4.2   | 4.7  | 5.1  |            |
| $f_T$         | Gain band width product   | $V_{CE} = -6V, I_E = 10mA$          |       | 150  |      | MHz        |

## TYPICAL CHARACTERISTICS

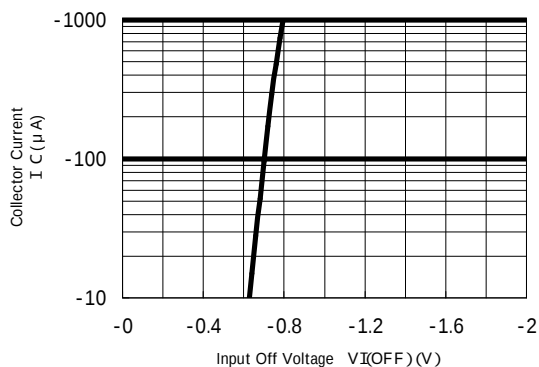
Input On Voltage - Collector Current



DC forward current gain-Collector Current



Collector Current - Input Off Voltage





*Marketing division, Marketing planning department*

6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

**Keep safety first in your circuit designs!**

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-flammable material or (3) prevention against any malfunction or mishap.

**Notes regarding these materials**

- These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party.
- ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.
- All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed herein.
- ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials.
- If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.
- Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.